



DMTH10H010LPS

#### 100V +175°C N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

#### **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> Max	Ι <sub>D</sub> T <sub>C</sub> = +25°C
100V	8.6mΩ @ V <sub>GS</sub> = 10V	98.4A

#### Description

This new generation N-Channel Enhancement Mode MOSFET is designed to minimize  $R_{DS(ON)}$ , yet maintain superior switching performance. This device is ideal for use in notebook battery power management and load switch.

### **Applications**

- Motor Control
- DC-DC Converters
- Power Management

#### Features

- Rated to +175°C Ideal for High Ambient Temperature Environments
- Thermally Efficient Package-Cooler Running Applications
- High Conversion Efficiency
- Low R<sub>DS(ON)</sub> Minimizes On-State Losses
- Low Input Capacitance
- Fast Switching Speed
- <1.1mm Package Profile Ideal for Thin Applications</p>
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

## **Mechanical Data**

- Case: PowerDI<sup>®</sup>5060-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram Below
- Terminal Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (£3)
- Weight: 0.097 grams (Approximate)

s [ D Pin1 SĨ ПD ПD s G Πр G S Top View Top View Bottom View Internal Schematic Pin Configuration

PowerDI5060-8

#### Ordering Information (Note 4)

	Part Number Case		Packaging		
	DMTH10H010LPS-13	PowerDI5060-8	2,500 / Tape & Reel		
Notes:	Notes: 1 ELL Directive 2002/95/EC (RoHS) & 2011/65/ELL (RoHS 2) compliant All applicable RoHS exemptions applied				

EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green"

See http://www and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

#### **Marking Information**



) | | = Manufacturer's Marking TH1010LS = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 17= 2017) WW = Week Code (01 to 53)

PowerDI is a registered trademark of Diodes Incorporated.



#### Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristi	Symbol	Value	Unit		
Drain-Source Voltage	V <sub>DSS</sub>	100	V		
Gate-Source Voltage			V <sub>GSS</sub>	±20	V
Continuous Drain Current ()/ 10\/)	Steady State	T <sub>A</sub> = +25°C T <sub>A</sub> = +100°C	ID	10.8 7.6	А
Continuous Drain Current (V <sub>GS</sub> = 10V)	Steady State	T <sub>C</sub> = +25°C T <sub>C</sub> = +100°C	ID	98.4 69.6	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)			I <sub>DM</sub>	250	A
Maximum Continuous Body Diode Forward Current			ls	95	А
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%)			I <sub>SM</sub>	250	А
Avalanche Current, L=0.3mH			I <sub>AS</sub>	15	А
Avalanche Energy, L=0.3mH			E <sub>AS</sub>	33.7	mJ

#### **Thermal Characteristics**

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)		PD	1.5	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	R <sub>0JA</sub>	99	°C/W
Total Power Dissipation	T <sub>C</sub> = +25°C	PD	125	W
Thermal Resistance, Junction to Case	R <sub>θJC</sub>	1.2	°C/W	
Operating and Storage Temperature Range	T <sub>J,</sub> T <sub>STG</sub>	-55 to +175	°C	

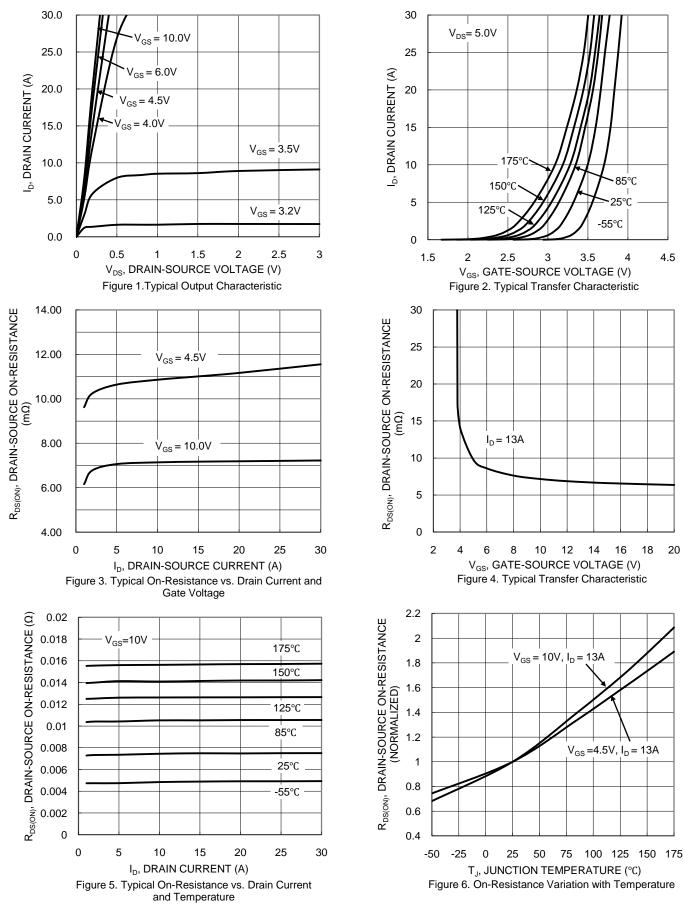
# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 6)	······			•	•	-	
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	100	—	—	V	$V_{GS} = 0V$ , $I_D = 1mA$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_	—	1	μA	$V_{DS} = 80V, V_{GS} = 0V$	
Gate-Source Leakage	IGSS	_	—	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 6)				-			
Gate Threshold Voltage	V <sub>GS(TH)</sub>	1.4	1.9	3	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
		_	6.9	8.6		$V_{GS} = 10V, I_D = 13A$	
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	—	7.5	12	mΩ	$V_{GS} = 6V, I_D = 13A$	
		_	10	20		$V_{GS} = 4.5V, I_D = 5A$	
Diode Forward Voltage	V <sub>SD</sub>	—	0.8	1.3	V	V <sub>GS</sub> = 0V, I <sub>S</sub> = 13A	
DYNAMIC CHARACTERISTICS (Note 7)							
Input Capacitance	Ciss	_	2592	—		V <sub>DS</sub> = 50V, V <sub>GS</sub> = 0V f = 1MHz	
Output Capacitance	C <sub>oss</sub>	—	792	_	pF		
Reverse Transfer Capacitance	Crss	—	45	_			
Gate Resistance	R <sub>g</sub>	—	2	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge	Qg	_	53.7	_		V 50V L 40A	
Gate-Source Charge	Q <sub>gs</sub>	_	10.6	_	nC	$V_{DD} = 50V, I_D = 13A,$	
Gate-Drain Charge	Q <sub>gd</sub>	_	8.2	_		$V_{GS} = 10V$	
Turn-On Delay Time	t <sub>D(ON)</sub>	_	11.6	_			
Turn-On Rise Time	t <sub>R</sub>	_	14.1	_		$V_{DD} = 50V, V_{GS} = 10V,$	
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	42.9	—	ns	$I_D = 13A, R_g = 6\Omega$	
Turn-Off Fall Time	tF	_	22	—	]	-	
Reverse Recovery Time	t <sub>RR</sub>	_	49.8	—	ns		
Reverse Recovery Charge	Q <sub>RR</sub>	_	85.1	—	nC	$I_F = 13A, di/dt = 100A/\mu s$	

 Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing. Notes:

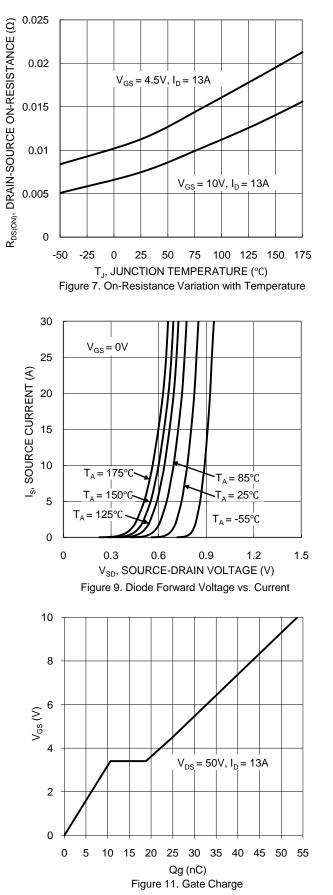


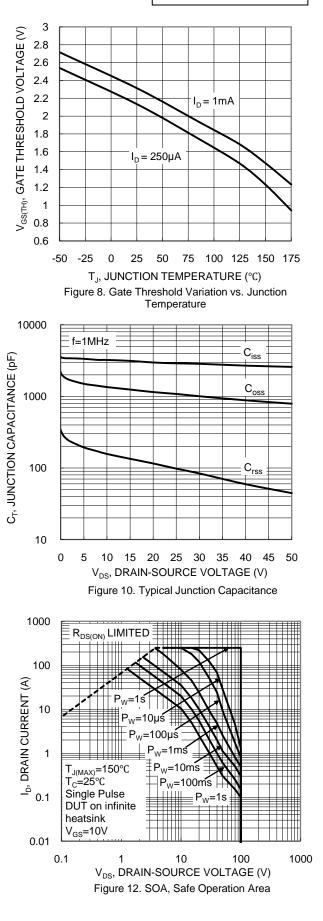
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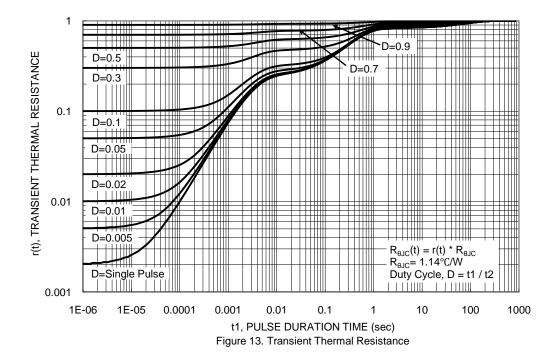






DMTH10H010LPS Document number: DS39907 Rev. 3 - 2



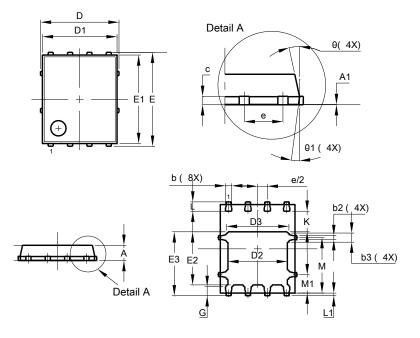




## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### PowerDI5060-8

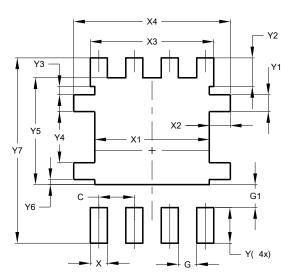


PowerDI5060-8						
Dim	Min Max Typ					
Α	0.90	1.10	1.00			
A1	0.00	0.05	-			
b	0.33	0.51	0.41			
b2	0.200	0.350	0.273			
b3	0.40	0.80	0.60			
C	0.230	0.330	0.277			
D	ļ	5.15 BSC	;			
D1	4.70	5.10	4.90			
D2	3.70	4.10	3.90			
D3	3.90	3.90 4.30 4.10				
E	6.15 BSC					
E1	5.60	6.00	5.80			
E2	3.28	3.68	3.48			
E3	3.99	4.39 4.19				
е	1.27 BSC					
G	0.51	0.71 0.6				
K	0.51					
L	0.51	0.71 0.61				
L1	0.100	0.200 0.17				
М	3.235	4.035 3.63				
M1	1.00	1.40	1.21			
θ	10º	12º	11º			
θ1	6°	8º	7°			
Al	All Dimensions in mm					

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8



Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
Х	0.610
X1	4.100
X2	0.755
X3	4.420
X4	5.610
Y	1.270
Y1	0.600
Y2	1.020
Y3	0.295
Y4	1.825
Y5	3.810
Y6	0.180
Y7	6.610



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